

TC7SU04F, TC7SU04FU

INVERTER

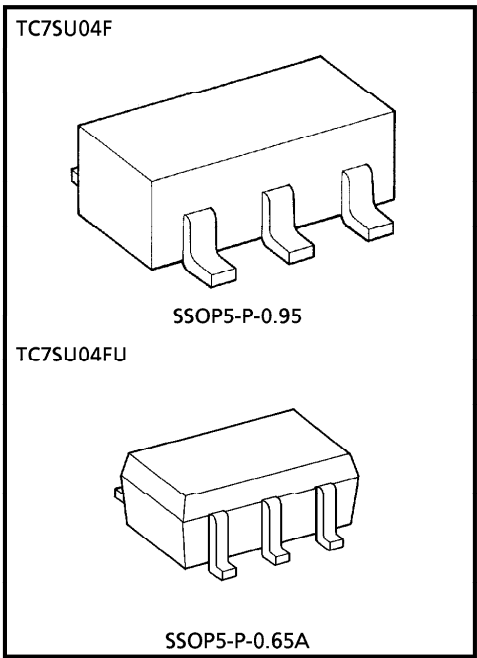
The TC7SU04 is a high speed C²MOS INVERTER fabricated with silicon gate C²MOS technology.
It achieves high speed operation similar to equivalent LSTTL while maintaining the C²MOS low power dissipation.
The internal circuit is composed of single stages inverter, it can be applied for crystal oscillation.
The input is equipped with protection circuits against static discharge or transient excess voltage.
Output currents are 1/2 compared to TC74HC series models.

FEATURES

- High Speed $t_{pd} = 7ns$ (Typ.) at $V_{CC} = 5V$
- Low Power Dissipation $I_{CC} = 1\mu A$ (Max.) at $T_a = 25^{\circ}C$
- High Noise Immunity $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (Min.)
- Output Drive Capability 5 LSTTL Loads
- Symmetrical Output Impedance ... $|I_{OH}| = I_{OL} = 2mA$ (Min.)
- Balanced Propagation Delays $t_{pLH} \cong t_{pHL}$
- Wide Operating Voltage Range ... $V_{CC} (opr) = 2 \sim 6V$

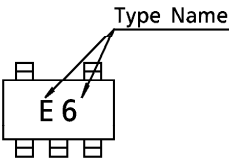
MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	V_{CC}	$-0.5 \sim 7$	V
DC Input Voltage	V_{IN}	$-0.5 \sim V_{CC} + 0.5$	V
DC Output Voltage	V_{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input Diode Current	I_{IK}	± 20	mA
Output Diode Current	I_{OK}	± 20	mA
DC Output Current	I_{OUT}	± 12.5	mA
DC V_{CC} / Ground Current	I_{CC}	± 25	mA
Power Dissipation	P_D	200	mW
Storage Temperature	T_{stg}	$-65 \sim 150$	$^{\circ}C$
Lead Temperature (10s)	T_L	260	$^{\circ}C$

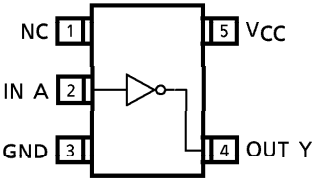


Weight SSOP5-P-0.95 : 0.016g (Typ.)
SSOP5-P-0.65A : 0.006g (Typ.)

MARKING



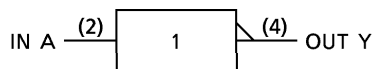
PIN ASSIGNMENT (TOP VIEW)



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LOGIC DIAGRAM



RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V_{CC}	2~6	V
Input Voltage	V_{IN}	0~ V_{CC}	V
Output Voltage	V_{OUT}	0~ V_{CC}	V
Operating Temperature	T_{opr}	-40~85	°C

DC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	TEST CONDITION		Ta = 25°C				Ta = - 40~85°C		UNIT
				V _{CC}	MIN.	TYP.	MAX.	MIN.	MAX.	
High-Level Input Voltage	V _{IH}	—		2.0 4.5 6.0	1.7 3.6 4.8	— — —	— — —	1.7 3.6 4.8	— — —	V
Low-Level Input Voltage	V _{IL}	—		2.0 4.5 6.0	— — —	— — —	0.3 0.9 1.2	— — —	0.3 0.9 1.2	V
High-Level Output Voltage	V _{OH}	V _{IN} = V _{IL}	I _{OH} = - 20μA	2.0	1.8	2.0	—	1.8	—	V
				4.5	4.0	4.5	—	4.0	—	
				6.0	5.5	5.9	—	5.5	—	
			I _{OH} = - 2mA I _{OH} = - 2.6mA	4.5 6.0	4.18 5.68	4.31 5.80	— —	4.13 5.63	— —	
Low-Level Output Voltage	V _{OL}	V _{IN} = V _{IH}		I _{OL} = 20μA	2.0	—	0.0	0.2	—	0.2
			4.5		—	0.0	0.2	—	0.5	
			6.0		—	0.0	0.5	—	0.5	
			I _{OL} = 2mA I _{OL} = 2.6mA	4.5 6.0	— —	0.17 0.18	0.26 0.26	— —	0.33 0.33	
Input Leakage Current	I _{IN}	V _{IN} = V _{CC} or GND		6.0	—	—	± 0.1	—	± 1.0	μA
Quiescent Supply Current	I _{CC}	V _{IN} = V _{CC} or GND		6.0	—	—	1.0	—	10.0	

Output currents are 1/2 compared to TC74HC series models.

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AC ELECTRICAL CHARACTERISTICS (CL = 15pF, Input tr = tf = 6ns, VCC = 5V)

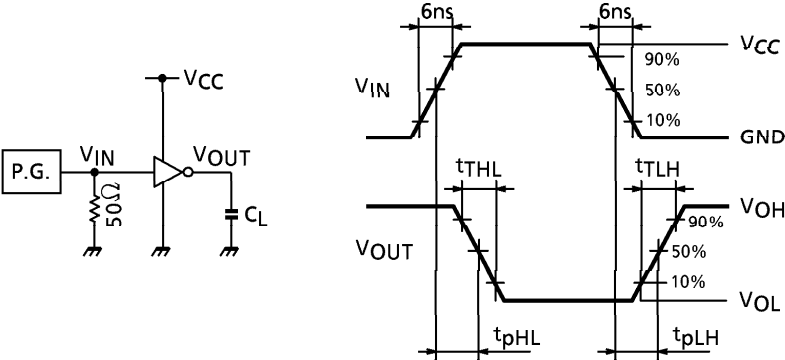
CHARACTERISTIC	SYMBOL	TEST CONDITION	Ta = 25°C			UNIT
			MIN.	TYP.	MAX.	
Output Transition Time	tTLH tTHL	—	—	5	10	ns
Propagation Delay Time	tPLH tPHL	—	—	7	15	ns

AC ELECTRICAL CHARACTERISTICS (CL = 50pF, Input tr = tf = 6ns)

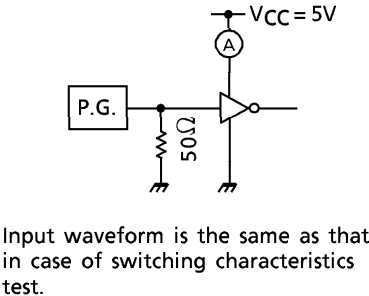
CHARACTERISTIC	SYMBOL	TEST CONDITION	Ta = 25°C			Ta = -40~85°C		UNIT
			VCC	MIN.	TYP.	MAX.	MIN.	MAX.
Output Transition Time	tTLH tTHL	—	2.0	—	50	125	—	155
			4.5	—	14	25	—	31
			6.0	—	12	21	—	26
Propagation Delay Time	tPLH tPHL	—	2.0	—	48	100	—	125
			4.5	—	12	20	—	25
			6.0	—	9	17	—	21
Input Capacitance	CIN	—	—	5	10	—	10	pF
Power Dissipation Capacitance	CPD	(Note 1)	—	10	—	—	—	

Note 1 : CPD defined as the value of internal equivalent capacitance of IC which is calculated from the operating current consumption without load (refer to Test Circuit).
Average operating current can be obtained by the equation hereunder.
 $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

SWITCHING CHARACTERISTICS TEST CIRCUIT

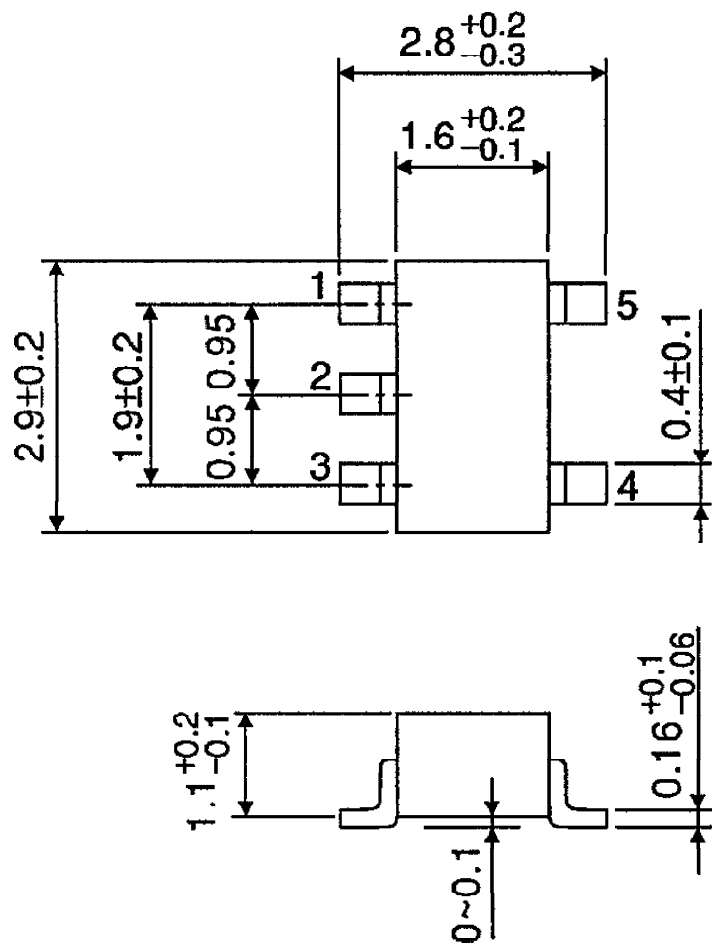


ICC (opr) TEST CIRCUIT



OUTLINE DRAWING
SSOP5-P-0.95

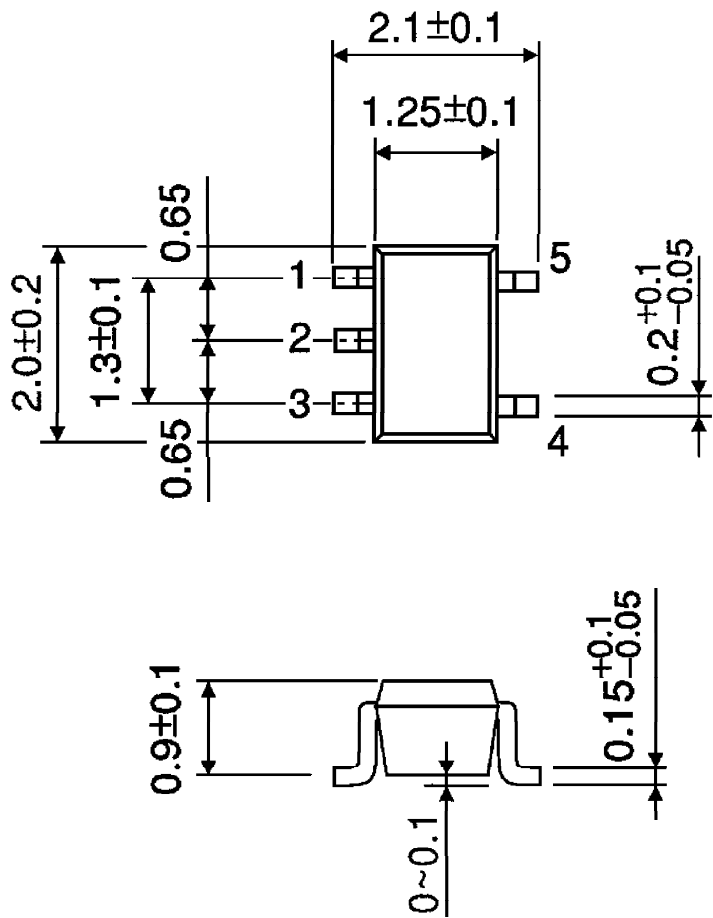
Unit : mm



Weight : 0.016g (Typ.)

OUTLINE DRAWING
SSOP5-P-0.65A

Unit : mm



Weight : 0.006g (Typ.)